

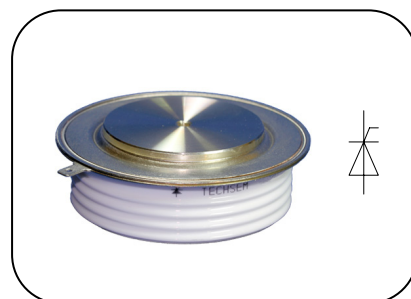
### Features

- Interdigitated amplifying gates
- Fast turn-on and high di/dt
- Low switching losses

### Typical Applications

- Inductive heating
- Electronic welders
- Self-commutated inverters

|                   |                                       |
|-------------------|---------------------------------------|
| $I_{T(AV)}$       | 1750A                                 |
| $V_{DRM}/V_{RRM}$ | 800~1800V                             |
| $t_q$             | 18~50 $\mu$ s                         |
| $I_{TSM}$         | 18 kA                                 |
| $I^2t$            | 1620 10 <sup>3</sup> A <sup>2</sup> S |



| SYMBOL                 | CHARACTERISTIC                                                       | TEST CONDITIONS                                                                                                                      | $T_J(^{\circ}\text{C})$ | VALUE |      |       | UNIT                             |
|------------------------|----------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------|-------------------------|-------|------|-------|----------------------------------|
|                        |                                                                      |                                                                                                                                      |                         | Min   | Type | Max   |                                  |
| $I_{T(AV)}$            | Mean on-state current                                                | 180° half sine wave 50Hz<br>Double side cooled,<br>$T_C=55^{\circ}\text{C}$                                                          | 125                     |       |      | 1750  | A                                |
| $V_{DRM}$<br>$V_{RRM}$ | Repetitive peak off-state voltage<br>Repetitive peak reverse voltage | $t_p=10\text{ms}$                                                                                                                    | 125                     | 800   |      | 1800  | V                                |
| $I_{DRM}$<br>$I_{RRM}$ | Repetitive peak current                                              | at $V_{DRM}$<br>at $V_{RRM}$                                                                                                         | 125                     |       |      | 120   | mA                               |
| $I_{TSM}$              | Surge on-state current                                               | 10ms half sine wave                                                                                                                  | 125                     |       |      | 18    | kA                               |
| $I^2t$                 | $I^2t$ for fusing coordination                                       | $V_R=0.6V_{RRM}$                                                                                                                     | 125                     |       |      | 1620  | A <sup>2</sup> s*10 <sup>3</sup> |
| $V_{TO}$               | Threshold voltage                                                    |                                                                                                                                      | 125                     |       |      | 1.48  | V                                |
| $r_T$                  | On-state slope resistance                                            |                                                                                                                                      | 125                     |       |      | 0.28  | m $\Omega$                       |
| $V_{TM}$               | Peak on-state voltage                                                | $I_{TM}=3000\text{A}$ , $F=28\text{kN}$                                                                                              | 25                      |       |      | 3.15  | V                                |
| dv/dt                  | Critical rate of rise of off-state voltage                           | $V_{DM}=0.67V_{DRM}$                                                                                                                 | 125                     |       |      | 1000  | V/ $\mu$ s                       |
| di/dt                  | Critical rate of rise of on-state current                            | $V_{DM}=67\%V_{DRM}$ to 2500A,<br>Gate pulse $t_r \leq 0.5\mu\text{s}$ $I_{GM}=1.5\text{A}$                                          | 125                     |       |      | 1200  | A/ $\mu$ s                       |
| $Q_{rr}$               | Recovery charge                                                      | $I_{TM}=2000\text{A}$ , $t_p=2000\mu\text{s}$ ,<br>$di/dt=-60\text{A}/\mu\text{s}$ , $V_R=50\text{V}$                                | 125                     |       | 800  |       | $\mu\text{C}$                    |
| $t_q$                  | Circuit commutated turn-off time                                     | $I_{TM}=1500\text{A}$ , $t_p=1000\mu\text{s}$ , $V_R=50\text{V}$<br>$dv/dt=30\text{V}/\mu\text{s}$ , $di/dt=-20\text{A}/\mu\text{s}$ | 125                     | 18    |      | 50    | $\mu\text{s}$                    |
| $I_{GT}$               | Gate trigger current                                                 | $V_A=12\text{V}$ , $I_A=1\text{A}$                                                                                                   | 25                      | 40    |      | 300   | mA                               |
| $V_{GT}$               | Gate trigger voltage                                                 |                                                                                                                                      |                         | 0.9   |      | 3.5   | V                                |
| $I_H$                  | Holding current                                                      |                                                                                                                                      |                         | 20    |      | 500   | mA                               |
| $V_{GD}$               | Non-trigger gate voltage                                             | $V_{DM}=67\%V_{DRM}$                                                                                                                 | 125                     | 0.3   |      |       | V                                |
| $R_{th(j-c)}$          | Thermal resistance<br>Junction to case                               | At 180° sine double side cooled<br>Clamping force 28kN                                                                               |                         |       |      | 0.016 | $^{\circ}\text{C}/\text{W}$      |
| $R_{th(c-h)}$          | Thermal resistance<br>case to heat sink                              |                                                                                                                                      |                         |       |      | 0.004 |                                  |
| $F_m$                  | Mounting force                                                       |                                                                                                                                      |                         | 21    |      | 30    | kN                               |
| $T_{stg}$              | Stored temperature                                                   |                                                                                                                                      |                         | -40   |      | 140   | $^{\circ}\text{C}$               |
| $W_t$                  | Weight                                                               |                                                                                                                                      |                         |       | 650  |       | g                                |
| Outline                | KT54cT60                                                             |                                                                                                                                      |                         |       |      |       |                                  |

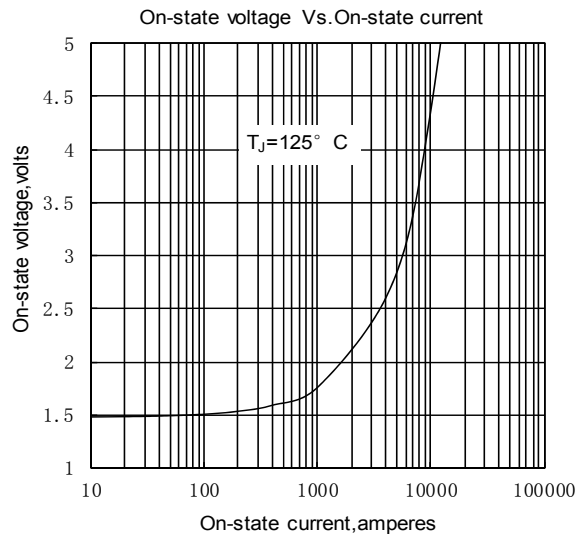


Fig. 1

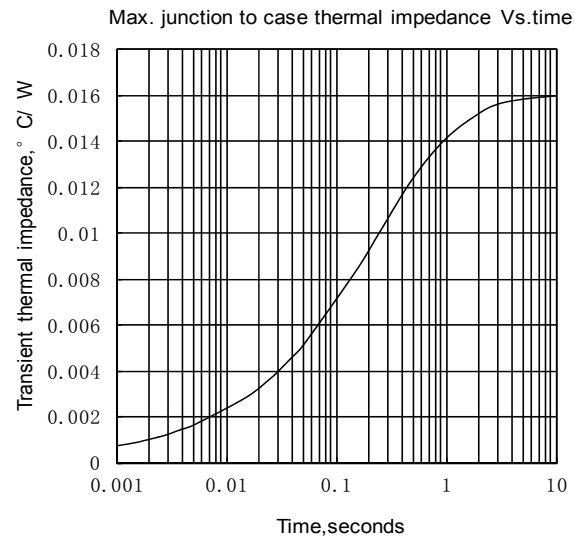


Fig. 2

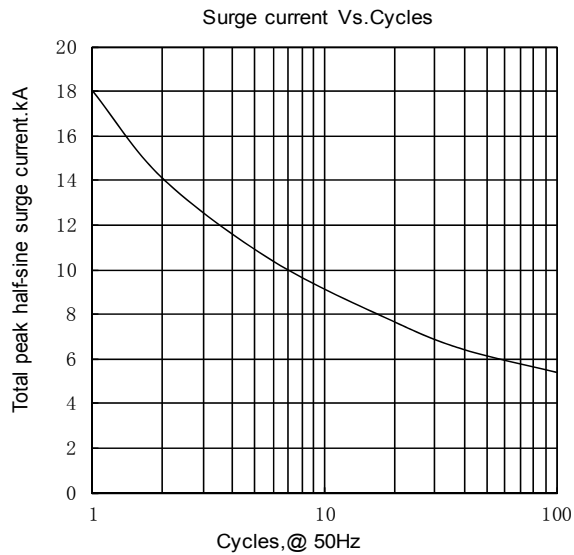


Fig. 3

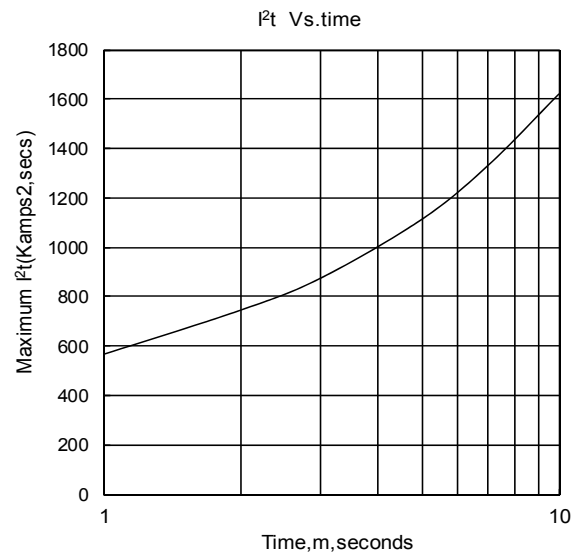


Fig. 4

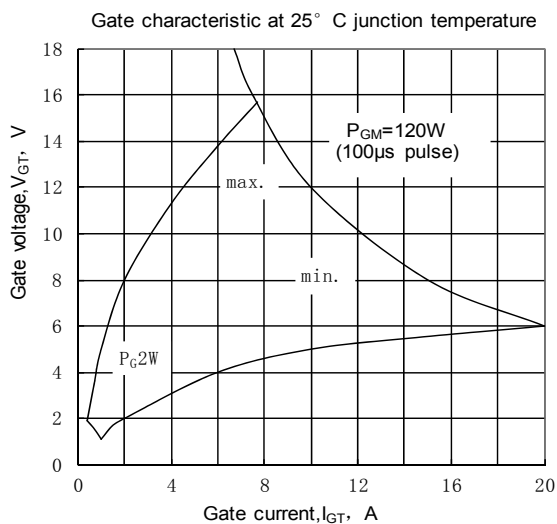


Fig. 5

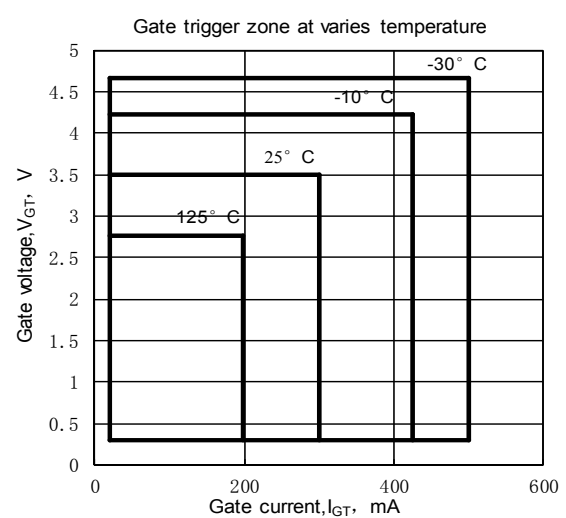


Fig. 6

## Outline:

